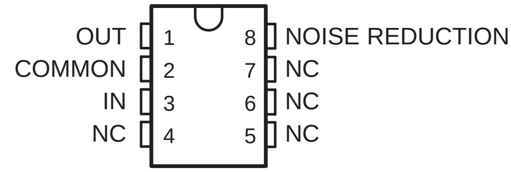
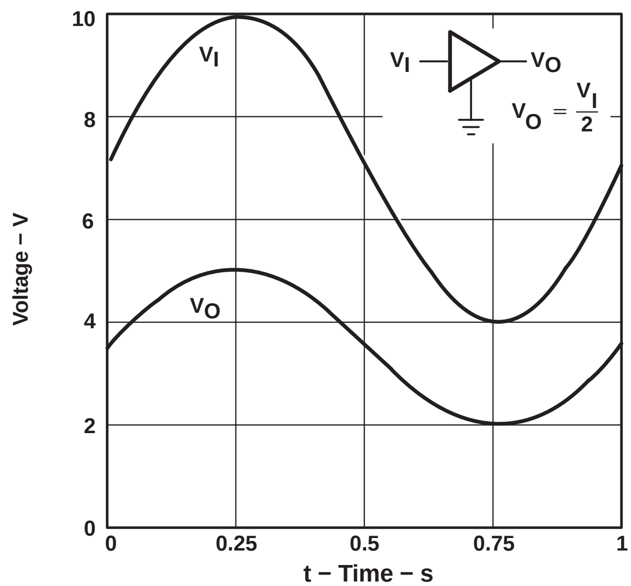
- **Qualified for Automotive Applications**
- **1/2 V_I Virtual Ground for Analog Systems**
- **Micropower Operation . . . 170 μA Typ, V_I = 5 V**
- **Wide V_I Range . . . 4 V to 40 V**
- **High Output-Current Capability**
  - **Source . . . 20 mA Typ**
  - **Sink . . . 20 mA Typ**
- **Excellent Output Regulation**
  - **−102 μV Typ at I_O = 0 to −10 mA**
  - **+49 μV Typ at I_O = 0 to +10 mA**
- **Low-Impedance Output . . . 0.0075 Ω Typ**
- **Noise Reduction Pin**

D PACKAGE
(TOP VIEW)



NC − No internal connection

INPUT/OUTPUT TRANSFER CHARACTERISTICS



description

In signal-conditioning applications utilizing a single power source, a reference voltage equal to one-half the supply voltage is required for termination of all analog signal grounds. Texas Instruments presents a precision virtual ground whose output voltage is always equal to one-half the input voltage, the TLE2426 *rail splitter*.

The unique combination of a high-performance, micropower operational amplifier and a precision-trimmed divider on a single silicon chip results in a precise V_O/V_I ratio of 0.5 while sinking and sourcing current. The TLE2426 provides a low-impedance output with 20 mA of sink and source capability while drawing less than 280 μA of supply current over the full input range of 4 V to 40 V. A designer need not pay the price in terms of board space for a conventional signal ground consisting of resistors, capacitors, operational amplifiers, and voltage references. For increased performance, the 8-pin package provides a noise-reduction pin. With the addition of an external capacitor (C_{NR}), peak-to-peak noise is reduced while line ripple rejection is improved.

Initial output tolerance for a single 5-V or 12-V system is better than 1% over the full 40-V input range. Ripple rejection exceeds 12 bits of accuracy. Whether the application is for a data acquisition front end, analog signal termination, or simply a precision voltage reference, the TLE2426 eliminates a major source of system error.

ORDERING INFORMATION†

T_A	PACKAGE‡		ORDERABLE PART NUMBER	TOP-SIDE MARKING
−40°C to 125°C	SOIC (D)	Tape and Reel	TLE2426QDRQ1	2426Q1

† For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at http://www.ti.com.
‡ Package drawings, thermal data, and symbolization are available at http://www.ti.com/packaging.

absolute maximum ratings over operating free-air temperature (unless otherwise noted)†

Continuous input voltage, V_I . . . . 40 V
Continuous filter trap voltage . . . . 40 V
Output current, I_O . . . . ±80 mA
Duration of short-circuit current at (or below) 25°C (see Note 1) . . . . unlimited
Continuous total power dissipation . . . . See Dissipation Rating Table
Operating free-air temperature range, T_A: Q suffix . . . . −40°C to 125°C
Storage temperature range, T_{stg} . . . . −65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds: D package . . . . . . 260°C

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The output may be shorted to either supply. Temperature and/or supply voltages must be limited to ensure that the maximum dissipation rating is not exceeded.

DISSIPATION RATING TABLE

PACKAGE	$T_A \le 25°C$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25°C$	$T_A = 70°C$ POWER RATING	$T_A = 85°C$ POWER RATING	$T_A = 125°C$ POWER RATING
D	1102 mV	10.3 mW/°C	638.5 mW	484 mW	72.1 mW

recommended operating conditions

	MIN	MAX	UNIT
Input voltage, V_I	4	40	V
Operating free-air temperature, T_A	−40	125	°C

electrical characteristics at specified free-air temperature, V_I = 5 V, I_O = 0 (unless otherwise noted)

PARAMETER	TEST CONDITIONS		T_A†	MIN	TYP	MAX	UNIT
Output voltage	V_I = 4 V		25°C	1.98	2	2.02	V
	V_I = 5 V			2.48	2.5	2.52	
	V_I = 40 V			19.8	20	20.2	
	V_I = 5 V		Full range	2.465		2.535	
Temperature coefficient of output voltage			Full range		25		ppm/°C
Supply current	No load	V_I = 5 V	25°C		170	300	μA
		V_I = 4 to 40 V	Full range			400	
Output voltage regulation (sourcing current)‡	I_O = 0 to −10 mA		25°C		−0.102	±0.7	mV
			Full range			±10	
	I_O = 0 to −20 mA		25°C		−0.121	±1.4	
Output voltage regulation (sinking current)‡	I_O = 0 to 10 mA		25°C		0.049	±0.5	mV
	I_O = 0 to 8 mA		Full range			±10	
	I_O = 0 to 20 mA		25°C		0.175	±1.4	
Output impedance‡			25°C		7.5	22.5	mΩ
Noise-reduction impedance			25°C		110		kΩ
Short-circuit current	Sinking current,	V_O = 5 V	25°C		26		mA
	Sourcing current,	V_O = 0			−47		
Output noise voltage, rms	f = 10 Hz to 10 kHz	C_{NR} = 0	25°C		120		μV
		C_{NR} = 1 μF			30		
Output voltage current step response	V_O to 0.1%, I_O = ±10 mA	C_L = 0	25°C		290		μs
		C_L = 100 pF			275		
	V_O to 0.01%, I_O = ±10 mA	C_L = 0	25°C		400		
		C_L = 100 pF			390		
Step response	V_I = 0 to 5 V, V_O to 0.1%	C_L = 100 pF	25°C		20		μs
	V_I = 0 to 5 V, V_O to 0.01%				120		

† Full range is −40°C to 125°C.
‡ The listed values are not production tested.

electrical characteristics at specified free-air temperature, V_I = 12 V, I_O = 0 (unless otherwise noted)

PARAMETER	TEST CONDITIONS		T_A†	MIN	TYP	MAX	UNIT
Output voltage	V_I = 4 V		25°C	1.98	2	2.02	V
	V_I = 12 V		25°C	5.95	6	6.05	V
	V_I = 40 V		25°C	19.8	20	20.2	V
	V_I = 12 V		Full range	5.925		6.075	V
Temperature coefficient of output voltage			Full range		35		ppm/°C
Supply current	No load	V_I = 12 V	25°C		195	300	μA
	No load	V_I = 4 to 40 V	Full range			400	μA
Output voltage regulation (sourcing current)‡	I_O = 0 to −10 mA		25°C		−1.48	±10	mV
	I_O = 0 to −10 mA		Full range			±10	mV
	I_O = 0 to −20 mA		25°C		−3.9	±10	mV
Output voltage regulation (sinking current)‡	I_O = 0 to 10 mA		25°C		2.27	±10	mV
	I_O = 0 to 8 mA		Full range			±10	mV
	I_O = 0 to 20 mA		25°C		4.3	±10	mV
Output impedance‡			25°C		7.5	22.5	mΩ
Noise-reduction impedance			25°C		110		kΩ
Short-circuit current	Sinking current,	V_O = 12 V	25°C		31		mA
	Sourcing current,	V_O = 0	25°C		−70		mA
Output noise voltage, rms	f = 10 Hz to 10 kHz	C_{NR} = 0	25°C		120		μV
	f = 10 Hz to 10 kHz	C_{NR} = 1 μF	25°C		30		μV
Output voltage current step response	V_O to 0.1%, I_O = ±10 mA	C_L = 0	25°C		290		μs
	V_O to 0.1%, I_O = ±10 mA	C_L = 100 pF	25°C		275		μs
	V_O to 0.01%, I_O = ±10 mA	C_L = 0	25°C		400		μs
	V_O to 0.01%, I_O = ±10 mA	C_L = 100 pF	25°C		390		μs
Step response	V_I = 0 to 12 V, V_O to 0.1%	C_L = 100 pF	25°C		12		μs
	V_I = 0 to 12 V, V_O to 0.01%	C_L = 100 pF	25°C		120		μs

† Full range is −40°C to 125°C.
‡ The listed values are not production tested.

TYPICAL CHARACTERISTICS

Table Of Graphs

		FIGURE
Output voltage	Distribution	1, 2
Output voltage change	vs Free-air temperature	3
Output voltage error	vs Input voltage	4
Input bias current	vs Input voltage	5
	vs Free-air temperature	6
Output voltage regulation	vs Output current	7
Output impedance	vs Frequency	8
Short-circuit output current	vs Input voltage	9, 10
	vs Free-air temperature	11, 12
Ripple rejection	vs Frequency	13
Spectral noise voltage density	vs Frequency	14
Output voltage response to output current step	vs Time	15
Output voltage power-up response	vs Time	16
Output current	vs Load capacitance	17

TYPICAL CHARACTERISTICS†

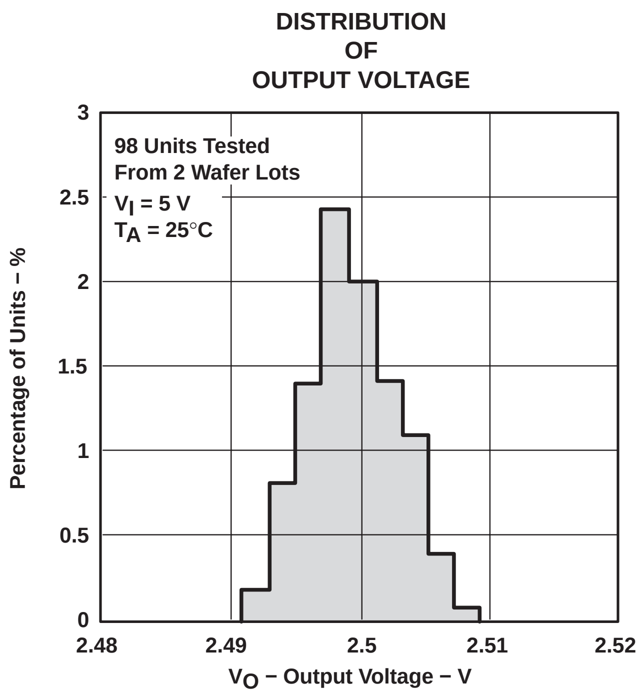


Figure 1

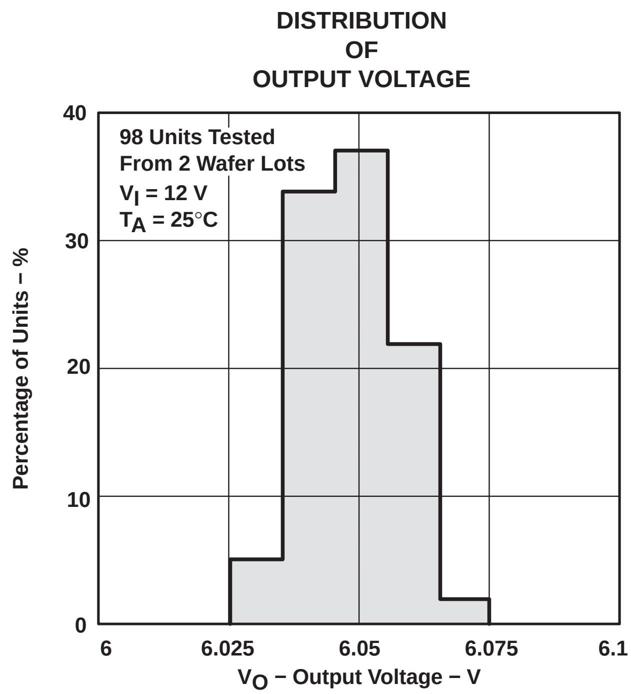


Figure 2

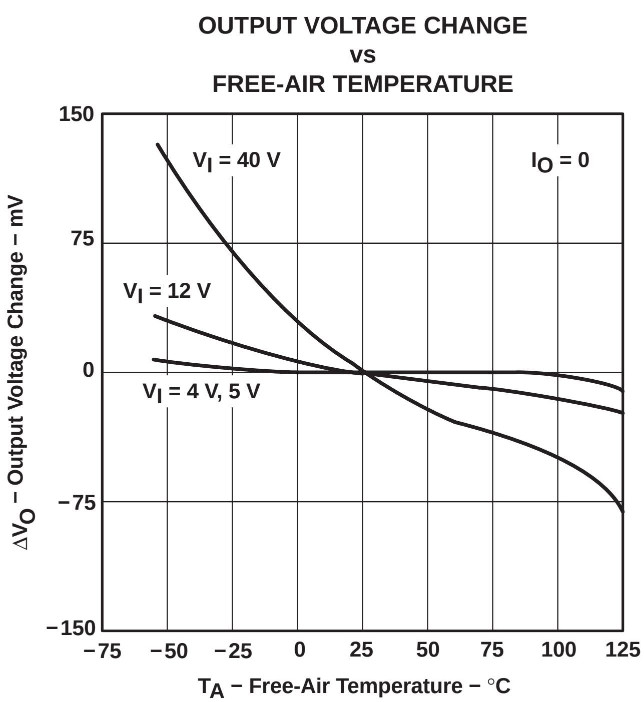


Figure 3

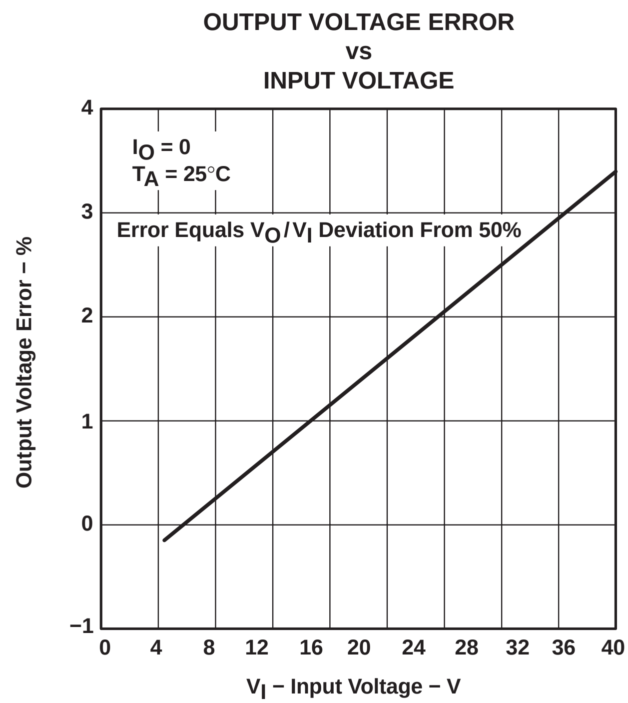


Figure 4

† Data at high and low temperatures are applicable within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS†

INPUT BIAS CURRENT vs INPUT VOLTAGE

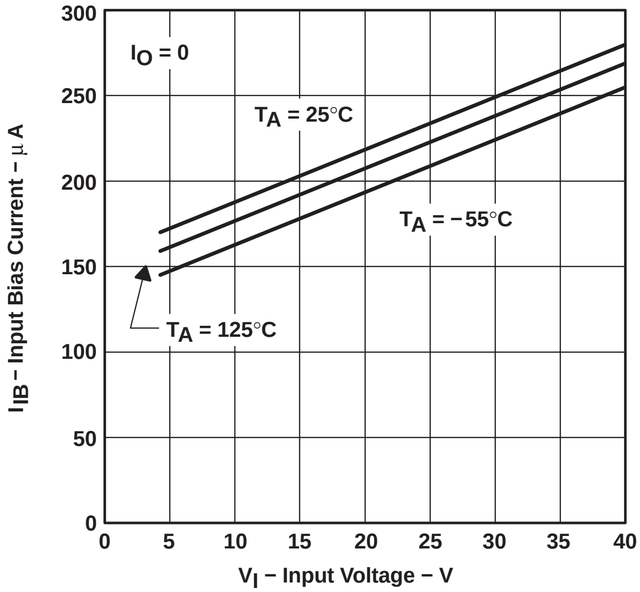


Figure 5

INPUT BIAS CURRENT vs FREE-AIR TEMPERATURE

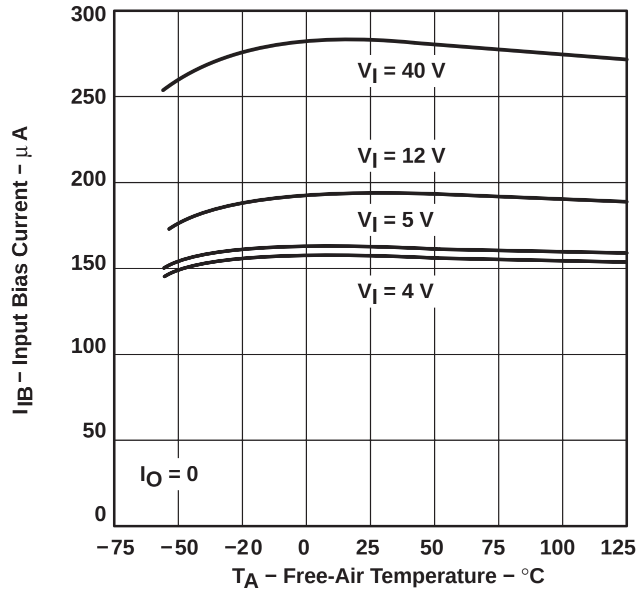


Figure 6

OUTPUT VOLTAGE REGULATION vs OUTPUT CURRENT

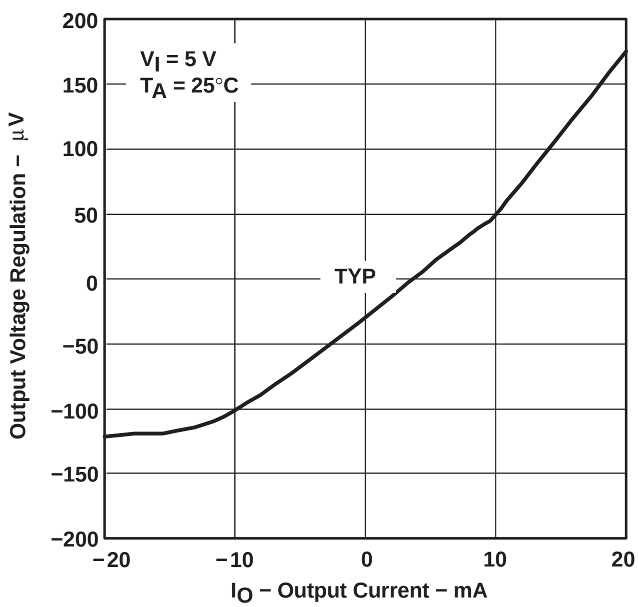


Figure 7

OUTPUT IMPEDANCE vs FREQUENCY

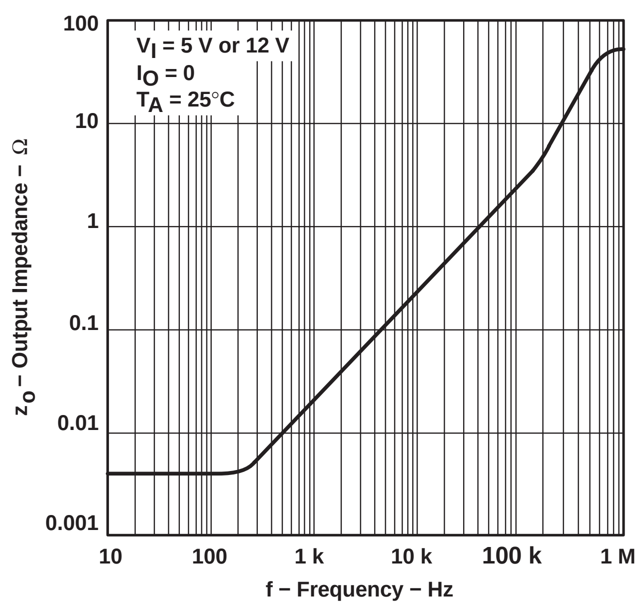


Figure 8

† Data at high and low temperatures are applicable within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS†

SHORT-CIRCUIT OUTPUT CURRENT vs INPUT VOLTAGE

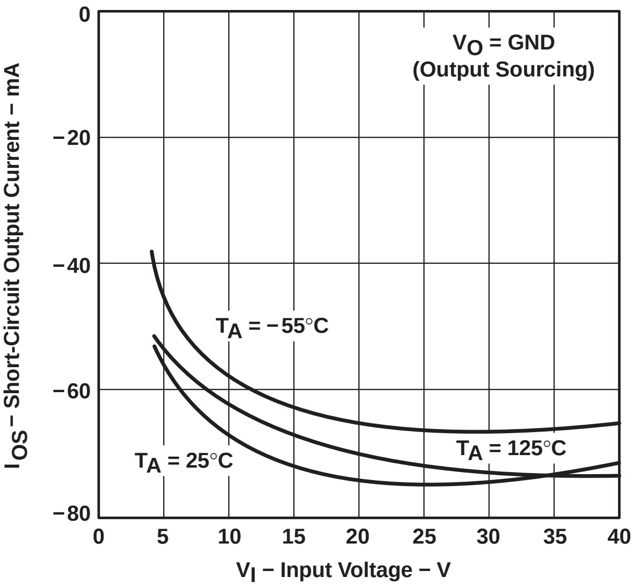


Figure 9

SHORT-CIRCUIT OUTPUT CURRENT vs INPUT VOLTAGE

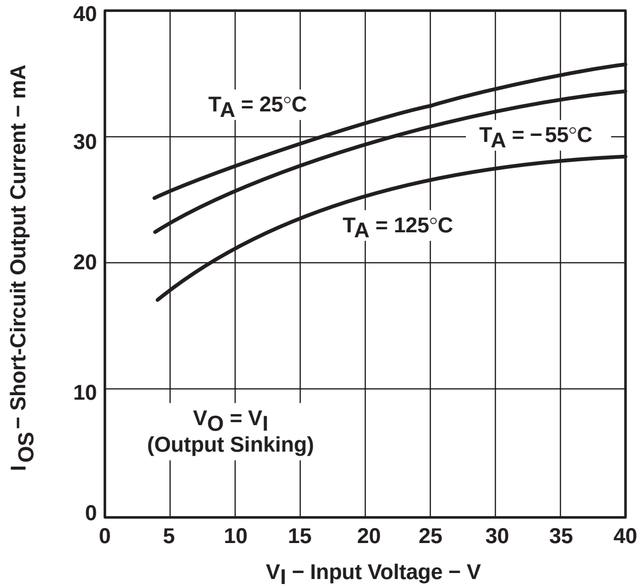


Figure 10

SHORT-CIRCUIT OUTPUT CURRENT vs FREE-AIR TEMPERATURE

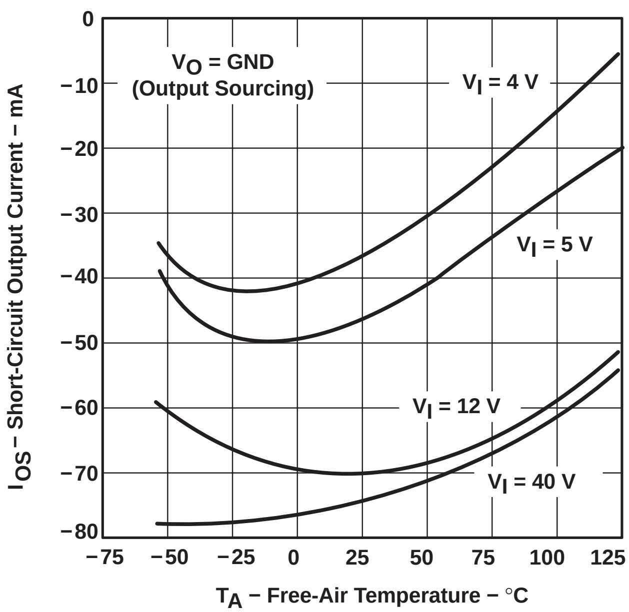


Figure 11

SHORT-CIRCUIT OUTPUT CURRENT vs FREE-AIR TEMPERATURE

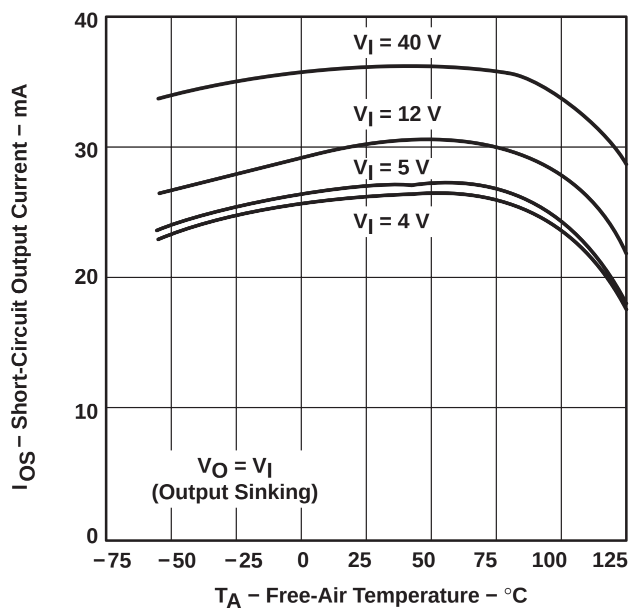


Figure 12

† Data at high and low temperatures are applicable within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

RIPPLE REJECTION
vs
FREQUENCY

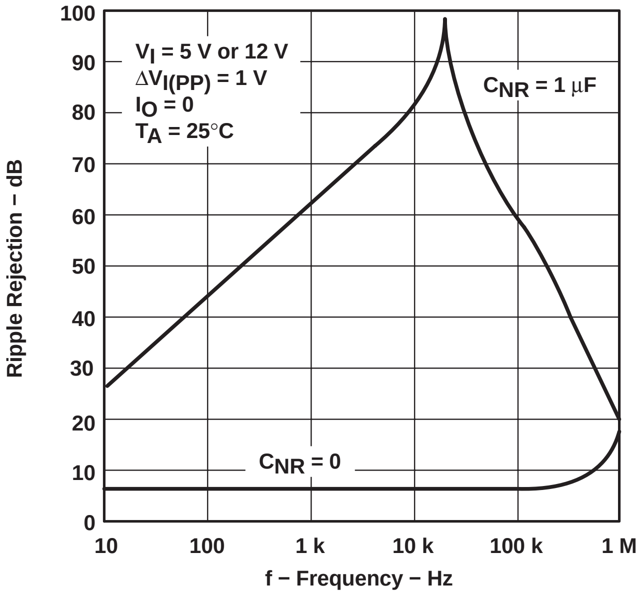


Figure 13

SPECTRAL NOISE VOLTAGE DENSITY
vs
FREQUENCY

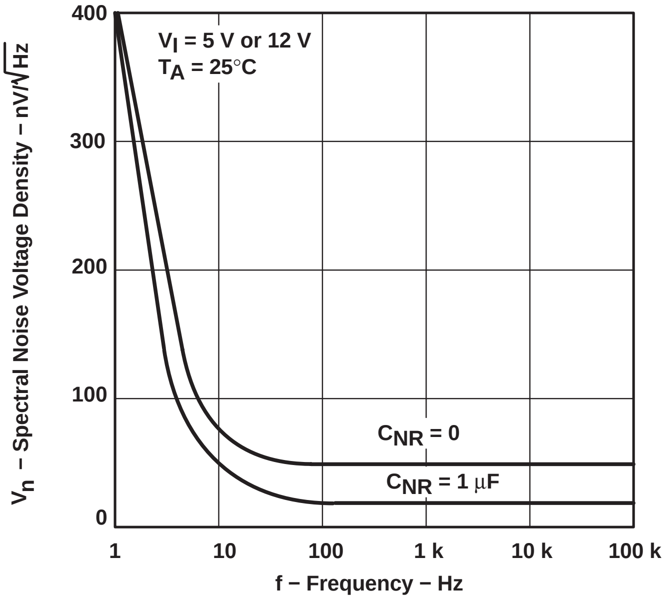


Figure 14

OUTPUT VOLTAGE RESPONSE
TO OUTPUT CURRENT STEP

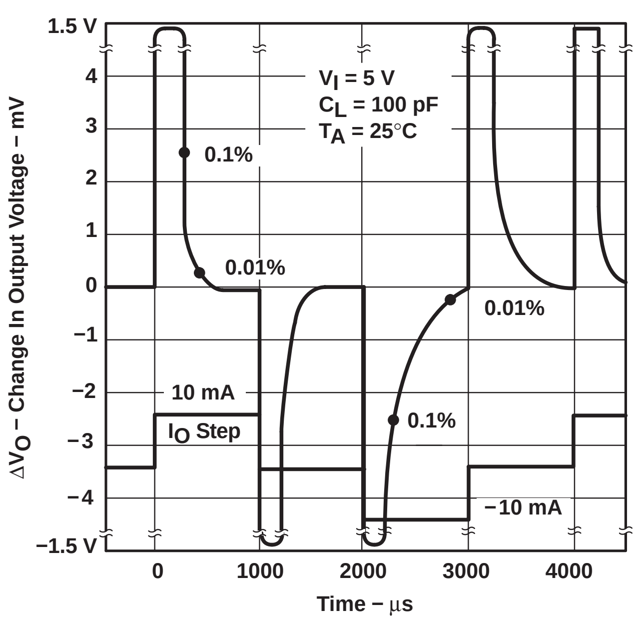


Figure 15

OUTPUT VOLTAGE POWER-UP RESPONSE

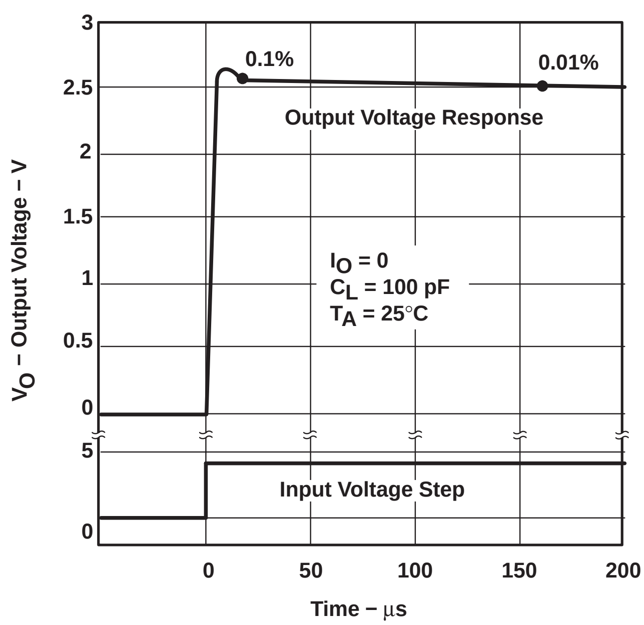


Figure 16

TYPICAL CHARACTERISTICS

STABILITY RANGE
OUTPUT CURRENT
vs
LOAD CAPACITANCE

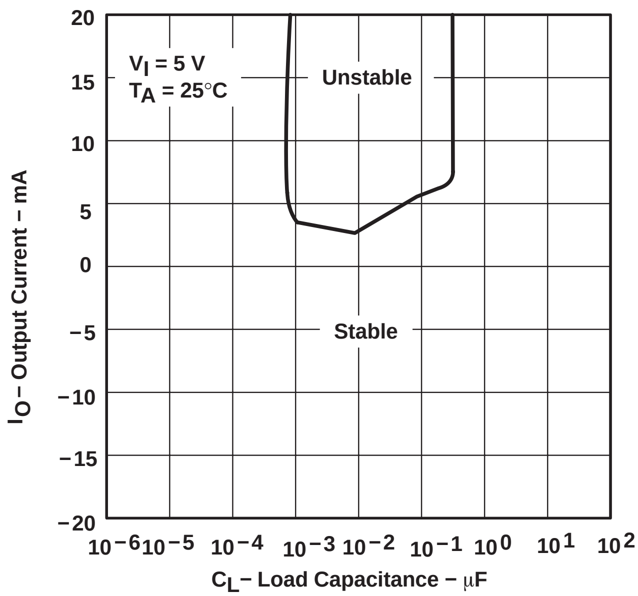


Figure 17

MACROMODEL INFORMATION

```
*   TLE2426 OPERATIONAL AMPLIFIER “MACROMODEL” SUBCIRCUIT
*   CREATED USING PARTS RELEASE 4.03 0N 08/21/90 AT 13:51
*   REV (N/A)     SUPPLY VOLTAGE: 5 V
*   CONNECTIONS:      FILTER
                      |   INPUT
*                     |   |   COMMON
*                     |   |   |   OUTPUT
*                     |   |   |   |
.SUBCKT TLE2426       1   3   4   5
```

```
   C1     11  12  21.66E-12
   C2      6   7  30.00E-12
   C3     87   0  10.64E-9
   CPSR   85  86  15.9E-9
   DCM+   81  82  DX
   DCM-   83  81  DX
   DC      5  53  DX
   DE     54   5  DX
   DLP    90  91  DX
   DLN    92  90  DX
   DP      4   3  DX
   ECMR   84  99  (2,99) 1
   EGND   99   0  POLY(2)   (3,0) (4,0)   0   .5  .5
   EPSR   85   0  POLY(1)   (3,4)  -16.22E-6 3.24E-6
   ENSE   89   2  POLY(1)   (88,0) 120E-6 1
   FB      7  99  POLY(6)   VB  VC  VE  VLP VLN VPSR 0 74.8E6 -10E6  10E6   10E6   -10E6  74E6
   GA      6   0  11  12  320.4E-6
   GCM     0   6  10  99  1.013E-9
   GPSR   85  86  (85,86)   100E-6
   GRC1    4  11  (4,11) 3.204E-4
   GRC2    4  12  (4,12) 3.204E-4
   GRE1   13  10  (13,10)   1.038E-3
   GRE2   14  10  (14,10)   1.038E-3
   HLIM   90   0  VLIM   1K
   HCMR   80   1  POLY(2)   VCM+   VCM-   0   1E2    1E2
   IRP     3   4  146E-6
   IEE     3  10  DC  24.05E-6
   IIO     2   0  .2E-9
   I1     88   0  1E-21
   Q1     11  89  13  QX
   Q2     12  80  14  QX
   R2      6   9  100.0E3
   RCM    84  81  1K
   REE    10  99   8.316E6
   RN1    87   0   2.55E8
   RN2    87  88  11.67E3
   RO1     8   5  63
   RO2     7  99  62
   VCM+   82  99  1.0
   VCM-   83  99  -2.3
   VB      9   0  DC  0
   VC      3  53  DC  1.400
   VE     54   4  DC  1.400
   VLIM    7   8  DC  0
   VLP    91   0  DC  30
   VLN     0  92  DC  30
   VPSR    0  86  DC  0
   RFB     5   2  1K
   RIN1    3   1  220K
   RIN2    1   4  220K
.MODEL DX  D(IS=800.OE-18)
.MODEL QX  PNP(IS=800.OE-18 BF=480)
.ENDS
```

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TLE2426QDRG4Q1	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2426Q1
TLE2426QDRG4Q1.A	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2426Q1

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

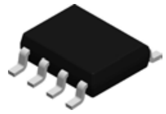
OTHER QUALIFIED VERSIONS OF TLE2426-Q1 :

- Catalog : TLE2426

- Enhanced Product : TLE2426-EP

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product
- Enhanced Product - Supports Defense, Aerospace and Medical Applications

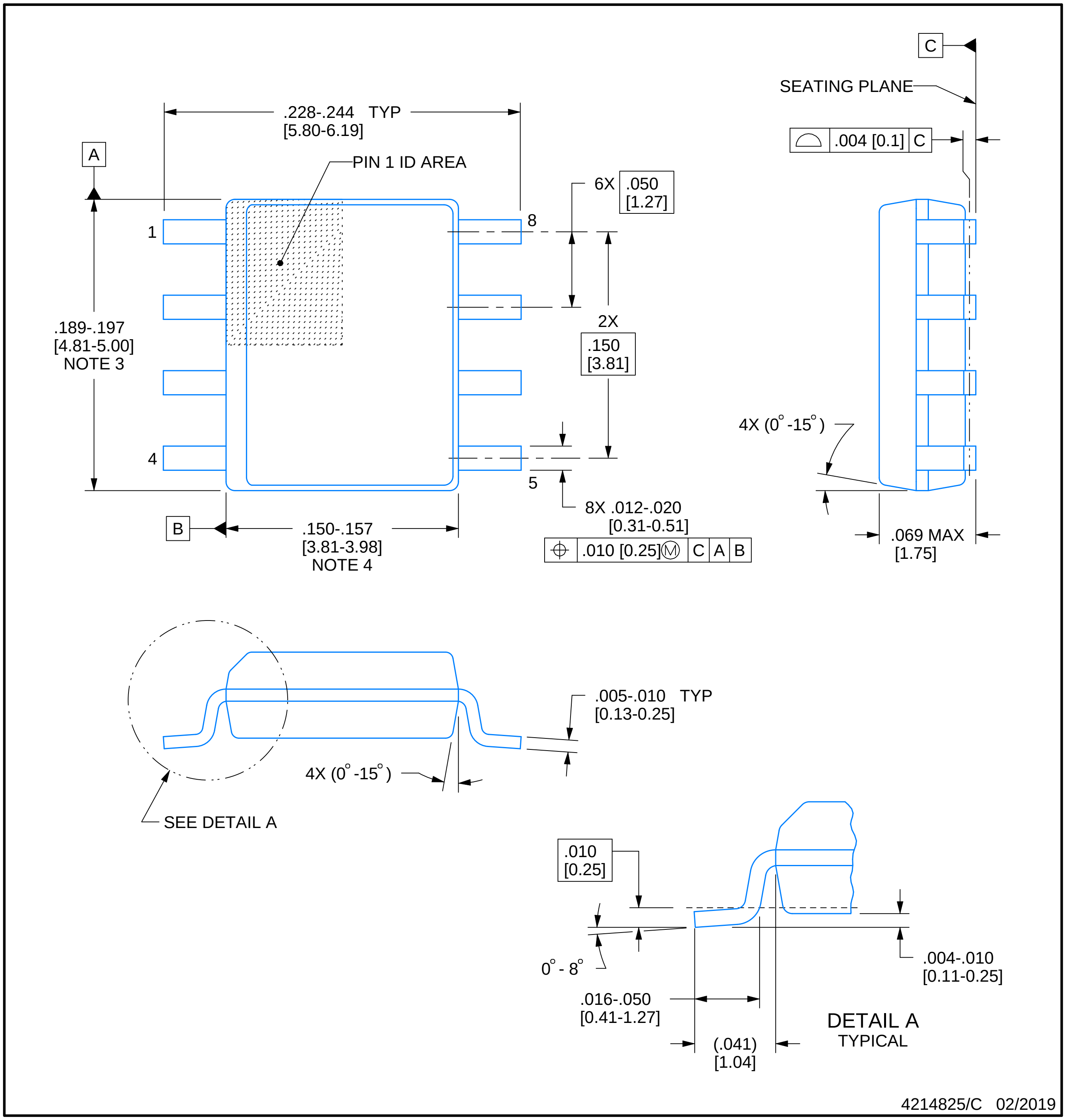


PACKAGE OUTLINE

D0008A

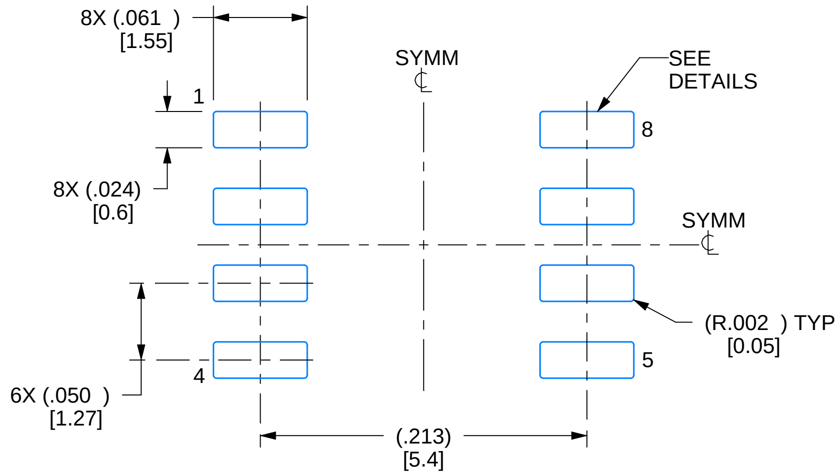
SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT

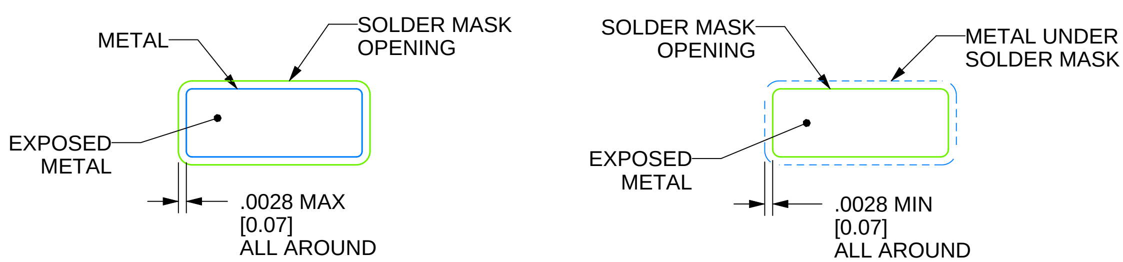


NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:8X



NON SOLDER MASK
DEFINED

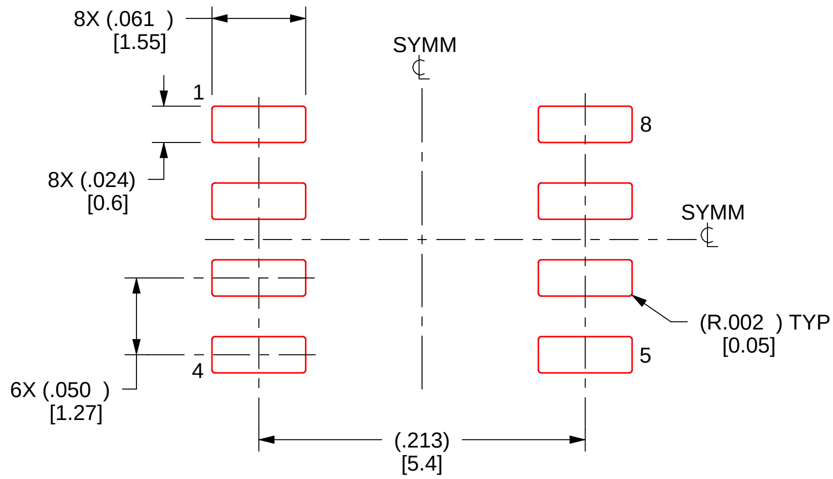
SOLDER MASK
DEFINED

SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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